AUK Semiconductor

STK0160F

Advanced Power MOSFET

SWITCHING REGULATOR APPLICATIONS

Features

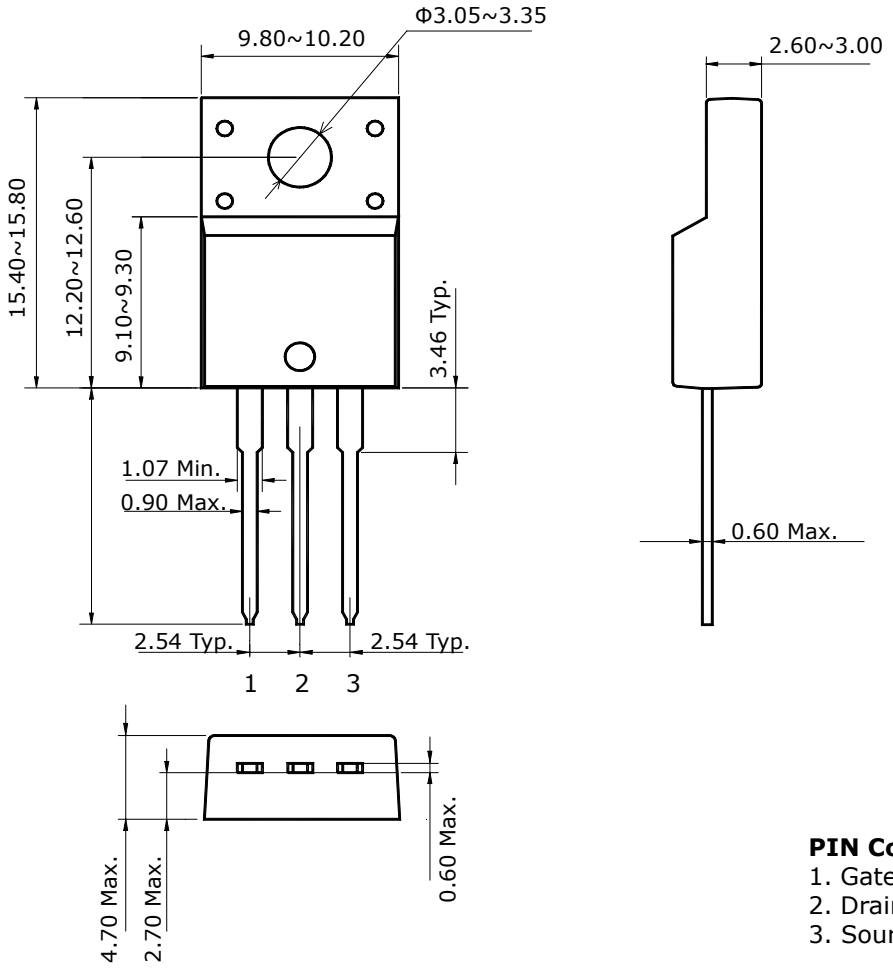
- High Voltage: BV_{DSS}=600V(Min.)
- Low C_{rss} : C_{rss}=4.3pF(Typ.)
- Low gate charge : Qg=4.5nC(Typ.)
- Low $R_{DS(on)}$:$R_{DS(on)}$=9.4Ω(Max.)

Ordering Information

Type NO.	Marking	Package Code
STK0160F	STK0160	TO-220F-3L

Outline Dimensions

unit : mm



PIN Connections
1. Gate
2. Drain
3. Source

Absolute maximum ratings (Tc=25°C)

Characteristic	Symbol		Rating	Unit
Drain-source voltage	V_{DSS}		600	V
Gate-source voltage	V_{GSS}		±30	V
Drain current (DC)	I_D	(Tc=25℃)	1.0	A
		(Tc=100℃)	0.8	A
Drain current (Pulsed) *	I_{DP}		4.0	A
Drain Power dissipation	P_D		18	W
Avalanche current (Single) ②	I_{AS}		1.0	A
Single pulsed avalanche energy ②	E_{AS}		22	mJ
Avalanche current (Repetitive) ①	I_{AR}		1.0	A
Repetitive avalanche energy ①	E_{AR}		2.5	mJ
Junction temperature	T_J		150	°C
Storage temperature range	T_{stg}		-55~150	

* Limited by maximum junction temperature

Characteristic		Symbol	Typ.	Max	Unit
Thermal resistance	Junction-case	$R_{th(J-C)}$	-	6.94	℃/W
	Junction-ambient	$R_{th(J-a)}$	-	62.5	

Electrical Characteristics (Tc=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Drain-source breakdown voltage	BV_{DSS}	I_D=250μA, V_{GS}=0	600	-	-	V
Gate-threshold voltage	$V_{GS(th)}$	I_D=250μA, V_{DS}= V_{GS}	2.0	-	4.0	V
Drain-source leakage current	I_{DSS}	V_{DS}=600V, V_{GS}=0V	-	-	1	μA
Gate-source leakage	I_{GSS}	V_{DS}=0V, V_{GS}=±30V	-	-	±100	nA
Drain-Source on-resistance ④	$R_{DS(ON)}$	V_{GS}=10V, I_D=0.5A	-	8.8	9.4	Ω
Forward transfer admittance ④	g_{fs}	V_{DS}=10V, I_D=0.5A	-	0.95	-	S
Input capacitance	Ciss	V_{GS}=0V, V_{DS}=25V, f=1MHz	-	150	225	pF
Output capacitance	Coss		-	20	30	
Reverse transfer capacitance	Crss		-	4.3	6.4	
Turn-on delay time	$t_{d(on)}$	V_{DD}=300V, V_{GS}=10V I_D=1.0A, R_G=25Ω ③④	-	22.5	-	ns
Rise time	t_r		-	27	-	
Turn-off delay time	$t_{d(off)}$		-	11.5	-	
Fall time	t_f		-	27	-	
Total gate charge	Q_g	V_{DD}=300V, V_{GS}=10V I_D=1.0A ③④	-	4.5	6.7	nC
Gate-source charge	Q_{gs}		-	0.9	1.3	
Gate-drain charge	Q_{gd}		-	1.3	1.9	

Source-Drain Diode Ratings and Characteristics (Tc=25°C)

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Continuous source current	I_S	Integral reverse diode in the MOSFET	-	-	1.0	A
Source current (Pulsed) ①	I_{SM}		-	-	4.0	
Forward voltage ④	V_{SD}	V_{GS}=0V, I_S=1.0A	-	-	1.4	V
Reverse recovery time	t_{rr}	I_s=1.0A, V_{GS}=0V di_s/dt=100A/us	-	160	-	ns
Reverse recovery charge	Q_{rr}		-	0.59	-	uC

Note ;

① Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature

② L=20mH, I_{AS}=1.0A, V_{DD}=50V, R_G=25Ω

③ Pulse Test : Pulse Width < 300us, Duty cycle≤ 2%

④ Essentially independent of operating temperature

Electrical Characteristic Curves

Fig. 1 I_D - V_{DS}

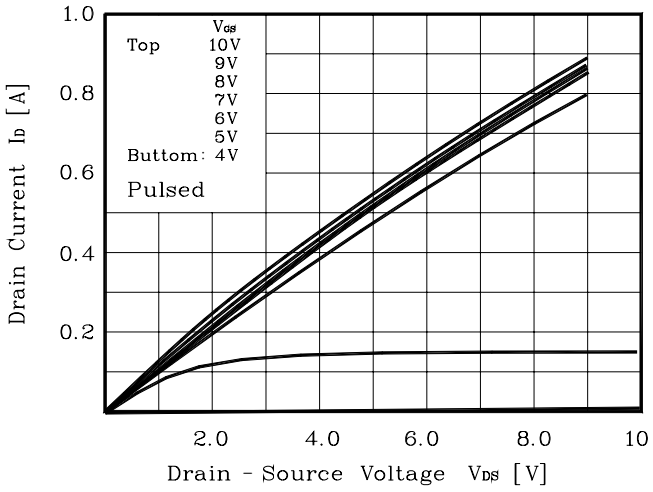


Fig. 2 I_D - V_{GS}

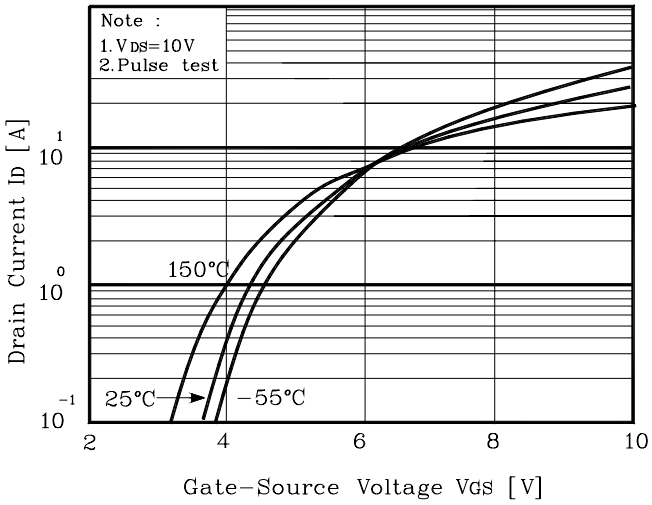


Fig. 3 $R_{DS(on)}$ - I_D

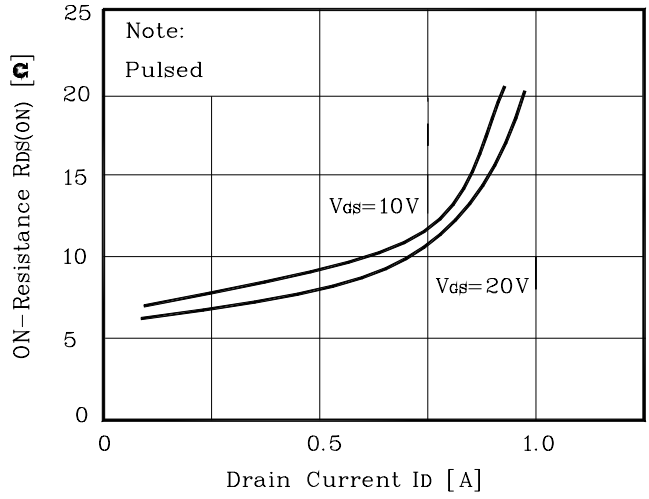


Fig. 4 I_S - V_{SD}

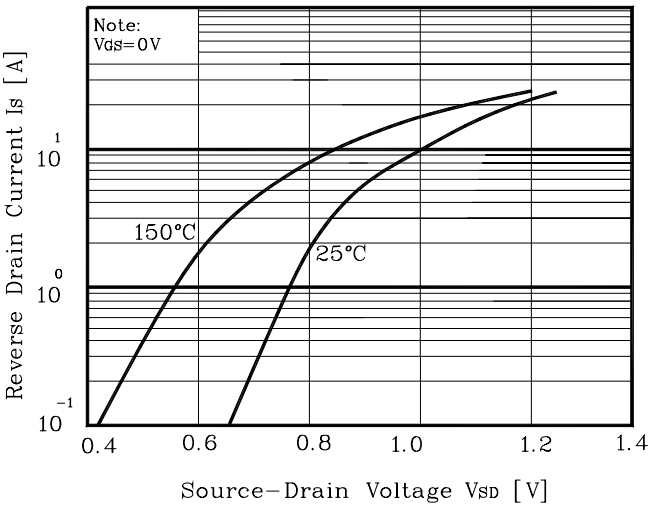


Fig. 5 Capacitance - V_{DS}

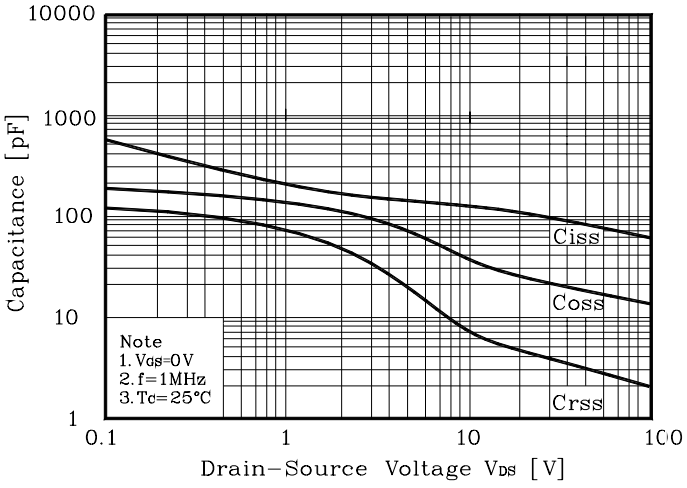


Fig. 6 V_{GS} - Q_G

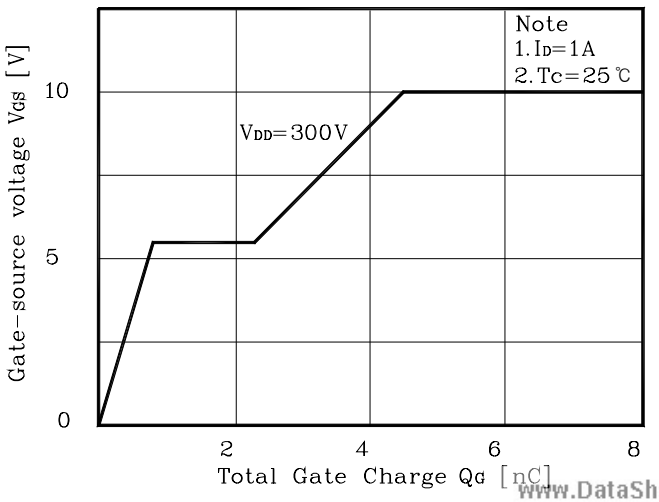


Fig. 7 V_{DSS} - T_J

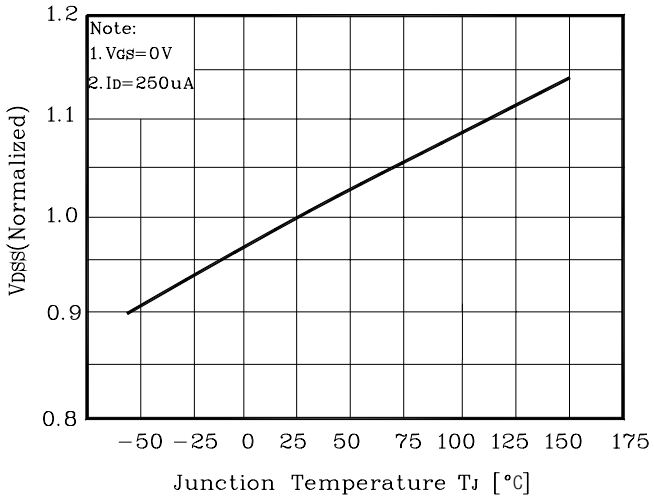


Fig. 8 $R_{DS(on)}$ - T_J

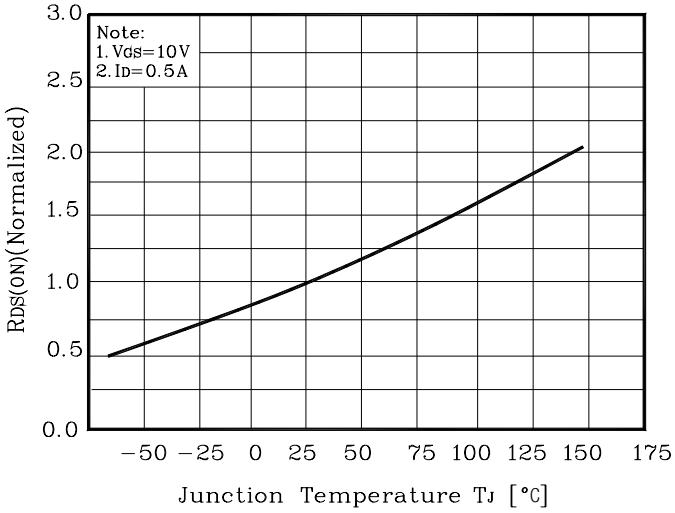


Fig. 9 I_D - T_C

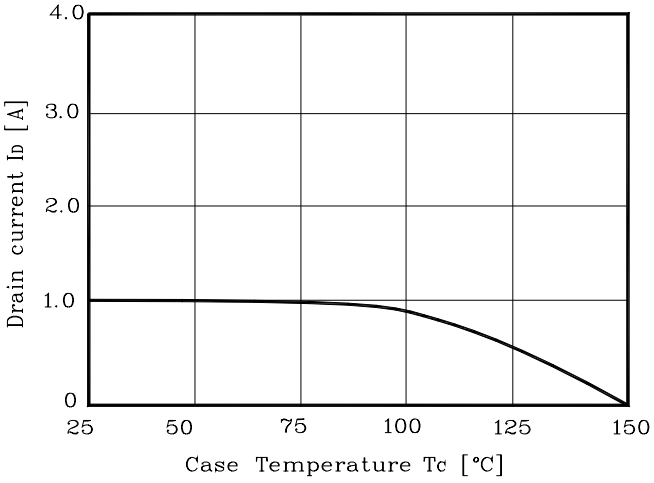


Fig. 10 Safe Operating Area

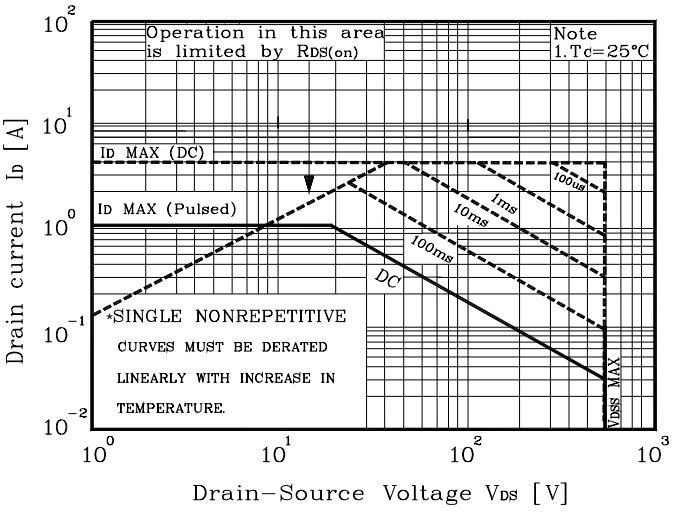


Fig. 11 Gate Charge Test Circuit & Waveform

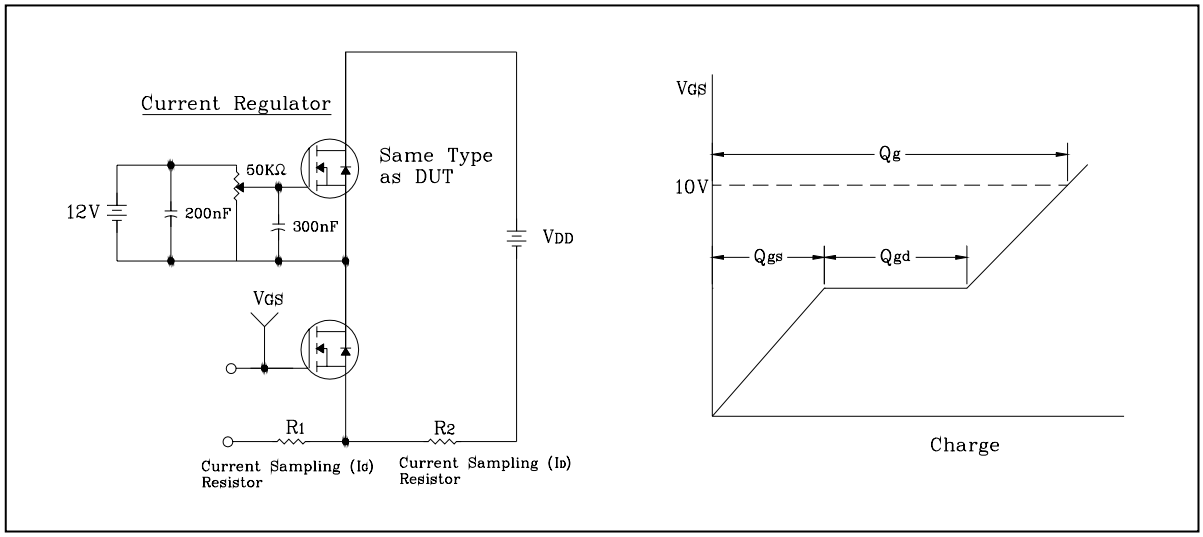


Fig. 12 Resistive Switching Test Circuit & Waveform

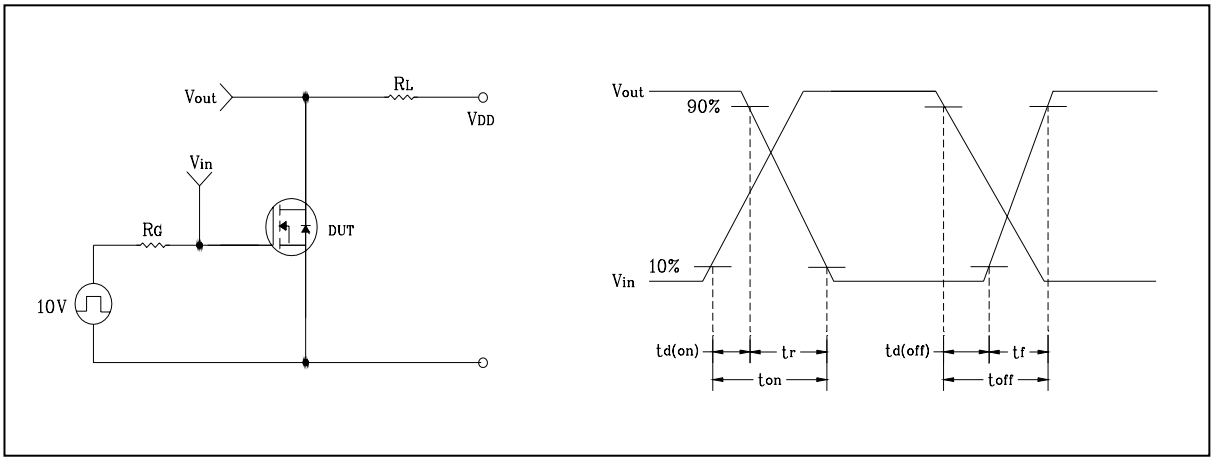


Fig. 13 E_{AS} Test Circuit & Waveform

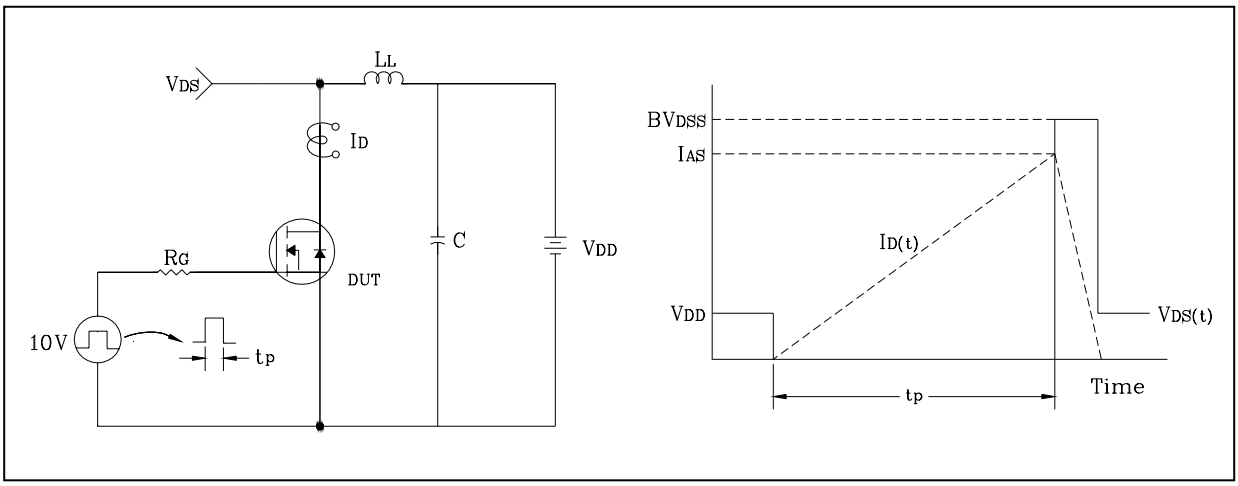
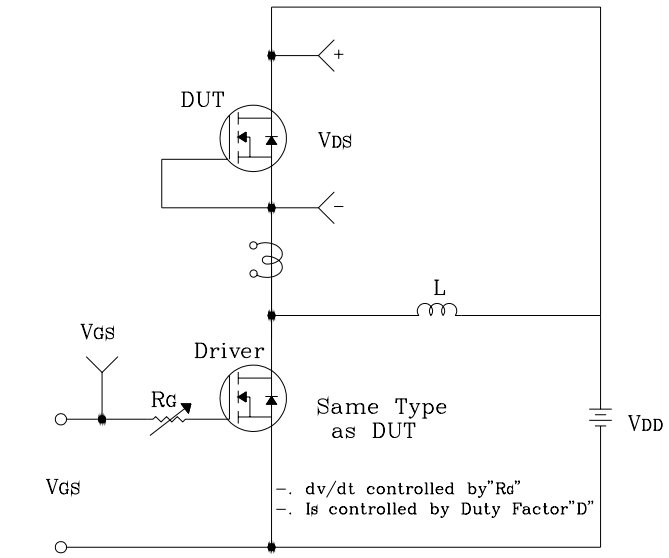
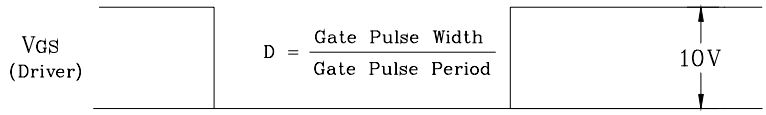
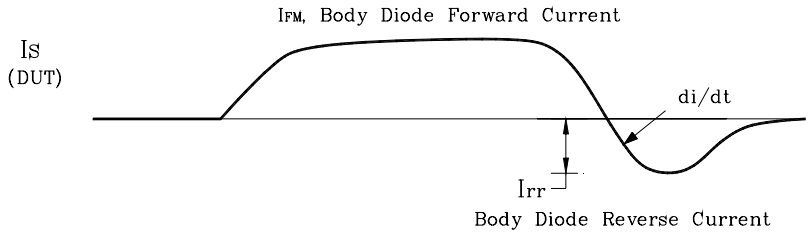
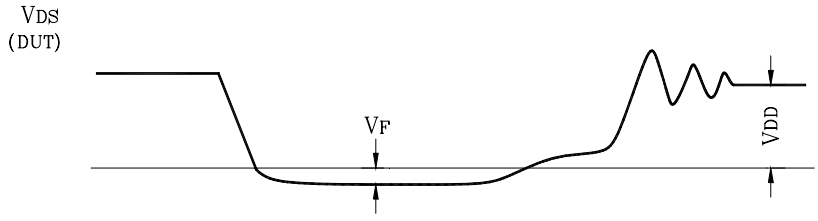


Fig. 14 Diode Reverse Recovery Time Test Circuit & Waveform









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